



SL54A SCHOTTKY RECTIFIER



Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Terminals finish: 100% Pure Tin
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	40	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _c =105°C, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	100	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.47	0.50	V
	V _{F2}	@ 5A, Pulse, T _J = 125℃	0.43	0.45	V
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 ℃	0.05	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_{R,} T_J = 100^{\circ}C$	-	30	mA
Junction Capacitance	Cj	$@V_R = 5.0 \text{ V}, \text{Tc=}25^{\circ}\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	170	280	pF

^{*} Pulse width < 300 µs, duty cycle < 2%

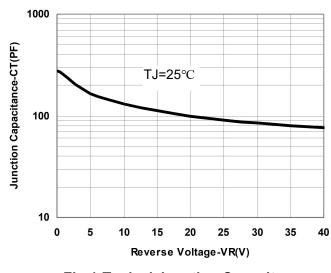




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R ₀ Jc	-	8	°C/W
Approximate Weight	wt	-	0.06	g

Ratings and Characteristics Curves



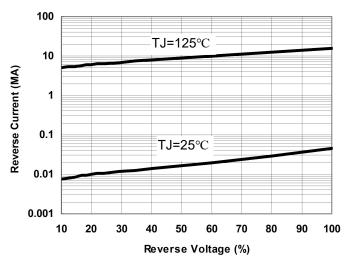


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

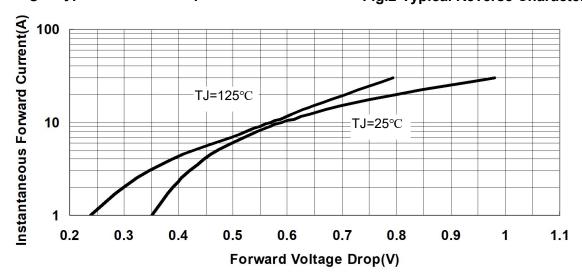


Fig.3-Typical Instantaneous Forward Voltage Characteristics

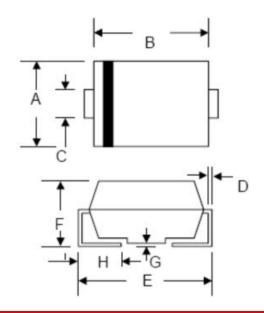
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Mechanical Dimensions SMA



SYMBOL	Millimeters		Inches		
STIVIBUL	Min.	Max.	Min.	Max.	
Α	2.40	2.84	0.094	0.112	
В	3.99	4.75	0.157	0.187	
С	1.05	1.70	0.041	0.067	
D	0.15	0.51	0.006	0.020	
Е	4.80	5.66	0.189	0.223	
F	1.90	2.95	0.075	0.116	
G	0.05	0.203	0.002	0.008	
Н	0.76	1.52	0.030	0.600	

Ordering Information

Device	Package	Shipping
SL54A	SMA	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 SL
 = Device Type

 5
 = Forward Current (5A)

 4
 = Reverse Voltage (40V)

 A
 = Package type

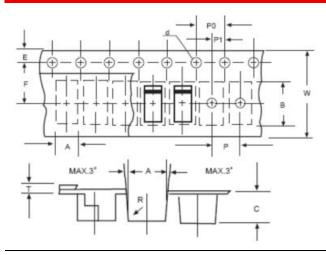
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification SMA



CVMDOL	Millimeters		
SYMBOL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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